Date Mailed: October 22, 2004 Sheet 1 of 1

Form 1449* INFORMATION DISCLOSURE STATEMENT IN AN APPLICATION	Docket Number: G&C 122.45-US-U1	Application Number: 10/723,976
	Applicant: Torsten Wipiejewski et al.	
	Filing Date: November 26, 2003	Group Art Unit: 2633

U.S. PATENT DOCUMENTS						
EXAMINER INITIAL	DOCUMENT NO.	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
DV	6,628,690	09/30/03	Fish et al.			
DV	6,614,819	09/02/03	Fish et al.			
DV	6,574,259	06/03/03	Fish et al.			

FOREIGN PATENTS							
	DOCUMENT NO.	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
						YES	NO

NON-PATENT DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)		

EXAMINER:	DATE CONSIDERED: 6/2005

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form for next communication to the Applicant.

*Substitute Disclosure Statement Form (PTO-1449) Patent and Trademark Office: U.S. DEPARTMENT OF COMMERCE

Date Faxed: January 28, 2005

Sheet 1 of 1

Form 1449* INFORMATION DISCLOSURE STATEMENT IN AN APPLICATION	Docket Number: G&C 122.45-US-U1	Application Number: 10/723,976
	Applicants: Torsten Wipiejewski et al.	
	Filing Date: November 26, 2003	Group Art Unit: 2883

U.S. PATENT DOCUMENTS						
EXAMINER INITIAL	DOCUMENT NO.	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE

FOREIGN PATENTS							
	DOCUMENT NO.	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES	TRANSLATION NO

NON-PATENT DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)		
EL		Aimez, V., et al., "Low-energy ion-implantation-induced quantum-well intermixing," IEEE Journal of Selected Topics in Quantum Electronics, 8:870-879, 2002
EL		Allard, M., et al., "Temperature determination in optoelectronic waveguide modulators," Journal of Lightwave Technology, 18:813-818, 2000
EL		Bian, Z., et al., "High-power operation of electro-absorption modulators," Applied Physics Letters, 83:3605-3607, 2003
EL		Claassen, M., et al., "Two-section electro-absorption modulator with negative chirp at low insertion loss," Electronics Lett., 32:2121-2122, 1996
EL		Hamoudi, A., et al., "Controlled disordering of compressively strained InGaAsP multiple quantum wells under SiO:P encapsulant and application to laser-modulator integration," Journal of Applied Physics, 78:5638-5641, 1995
EL		Jasmin, S., et al., "Diluted- and distributed- absorption microwave waveguide photodiodes for high efficiency and high power," IEEE Transactions on Microwave Theory and Techniques, 45:1337-1341, 1997
EL		Mason, B., et al., "40-Gb/s Tandem Electro-absorption Modulator," IEEE Photon. Techn. Lett., 14:27-29, 2002
EL		Murthy, S., et al., "A novel monolithic distributed traveling-wave photodetector with parallel optical feed," IEEE Photonics Technology Letters, 12:681-683, 2000
EL		Nespola, A., et al., "Analysis of failure mechanisms in velocity-matched distributed photodetectors," IEE Proc. Optoelectron, 146:25-30, 1999
EL		Shi, J.-W., et al., "Theory and design of a tapered line distributed photodetector," Journal of Lightwave Technology, 20:1942-1950, 2002
EL		Wipiejewski, T., et al., "Improved Performance of Vertical-Cavity Surface-Emitting Laser Diodes with Au-Plated Heat Spreading Layer," Electronics Lett., 31:279-281, 1995
EL		Wipiejewski, T., et al., "Monolithic Integration of a Widely Tunable Laser Diode with a High Speed Electro-Absorption Modulator," 52nd ECTC, San Diego, May 2002

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G&C 122.45-US-U1

Date Faxed: March 28, 2005 Sheet 1 of 1

Form 1449*	Docket Number: G&C 122.45-US-U1	Application Number: 10/723,076
INFORMATION DISCLOSURE STATEMENT IN AN APPLICATION	Applicants: Torsten Wipiejewski et al.	
	Filing Date: November 26, 2003	Group Art Unit: 2883

U.S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NO.	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE

FOREIGN PATENTS

	DOCUMENT NO.	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES	TRANSLATION NO

NON-PATENT DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

EH		H. Tanaka et al., "Temperature dependence and input optical power tolerance of an InGaAsP electroabsorption modulator module," 1996. Optical and Quantum Electronics, 28:605-612

EXAMINER:	DATE CONSIDERED: 6/2005

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G&C 122.45-US-U1

Date Faxed: January 27, 2005 Sheet 1 of 1

Form 1449* INFORMATION DISCLOSURE STATEMENT IN AN APPLICATION	Docket Number: G&C 122.45-US-U1	Application Number: 10/723,976
	Applicants: Torsten Wipiejewski et al.	
	Filing Date: November 26, 2003	Group Art Unit: 2883

U.S. PATENT DOCUMENTS							
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EL		Binn, Z., et al., "High-power operation of electro-absorption modulators," Applied Physics Letters, 83:3605-3607, 2003
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EL		Hamoudi, A., et al., "Controlled disordering of compressively strained InGaAsP multiple quantum wells under SiO:P encapsulant and application to laser-modulator integration," Journal of Applied Physics, 78:5638-5641, 1995
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EL		Murthy, S., et al., "A novel monolithic distributed traveling-wave photodetector with parallel optical feed," IEEE Photonics Technology Letters, 12:681-683, 2000
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EL		Wipiejewski, T., et al., "Improved Performance of Vertical-Cavity Surface-Emitting Laser Diodes with Au-Plated Heat Spreading Layer," Electronics Lett., 31:279-281, 1995
EL		Wipiejewski, T., et al., "Monolithic Integration of a Widely Tunable Laser Diode with a High Speed Electro-Absorption Modulator," 52nd ECTC, San Diego, May 2002

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G&C 122.45-US-U1